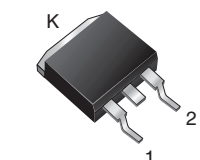


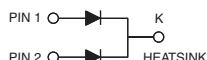
# Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.30\text{ V}$  at  $I_F = 5.0\text{ A}$

TMBS®  
D<sup>2</sup>PAK (TO-263AB)



VBT3045C



## DESIGN SUPPORT TOOLS

[click logo to get started](#)

**3D**  
Models  
Available

## PRIMARY CHARACTERISTICS

|                              |                               |
|------------------------------|-------------------------------|
| $I_{F(AV)}$                  | 2 x 15 A                      |
| $V_{RRM}$                    | 45 V                          |
| $I_{FSM}$                    | 200 A                         |
| $V_F$ at $I_F = 15\text{ A}$ | 0.39 V                        |
| $T_J$ max.                   | 150 °C                        |
| Package                      | D <sup>2</sup> PAK (TO-263AB) |
| Circuit configuration        | Common cathode                |

## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

## MECHANICAL DATA

**Case:** D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test

**Polarity:** as marked

## MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

| PARAMETER                                                                          | SYMBOL         | VBT3045C    | UNIT |
|------------------------------------------------------------------------------------|----------------|-------------|------|
| Maximum repetitive peak reverse voltage                                            | $V_{RRM}$      | 45          | V    |
| Maximum average forward rectified current<br>(fig. 1)                              | $I_{F(AV)}$    | 30          | A    |
|                                                                                    |                | 15          |      |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | $I_{FSM}$      | 200         | A    |
| Operating junction and storage temperature range                                   | $T_J, T_{STG}$ | -40 to +150 | °C   |

| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |                      |                                     |      |      |               |
|------------------------------------------------------------------------------------------------|----------------------|-------------------------------------|------|------|---------------|
| PARAMETER                                                                                      | TEST CONDITIONS      | SYMBOL                              | TYP. | MAX. | UNIT          |
| Instantaneous forward voltage per diode                                                        | $I_F = 5\text{ A}$   | $V_F^{(1)}$                         | 0.42 | -    | V             |
|                                                                                                | $I_F = 7.5\text{ A}$ |                                     | 0.44 | -    |               |
|                                                                                                | $I_F = 15\text{ A}$  |                                     | 0.49 | 0.57 |               |
|                                                                                                | $I_F = 5\text{ A}$   | $T_A = 125\text{ }^{\circ}\text{C}$ | 0.30 | -    |               |
|                                                                                                | $I_F = 7.5\text{ A}$ |                                     | 0.33 | -    |               |
|                                                                                                | $I_F = 15\text{ A}$  |                                     | 0.39 | 0.48 |               |
| Reverse current per diode                                                                      | $V_R = 45\text{ V}$  | $T_A = 25\text{ }^{\circ}\text{C}$  | -    | 2000 | $\mu\text{A}$ |
|                                                                                                |                      | $T_A = 125\text{ }^{\circ}\text{C}$ | 17   | 50   | mA            |

**Notes**

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 40\text{ ms}$ 

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |                 |           |                      |
|---------------------------------------------------------------------------------------------|-----------------|-----------|----------------------|
| PARAMETER                                                                                   | SYMBOL          | VB T3045C | UNIT                 |
| Typical thermal resistance                                                                  | $R_{\theta JC}$ | 1.6       | $^{\circ}\text{C/W}$ |
|                                                                                             |                 | 0.85      |                      |

| <b>ORDERING INFORMATION</b> (Example) |                 |                 |              |               |               |
|---------------------------------------|-----------------|-----------------|--------------|---------------|---------------|
| PACKAGE                               | PREFERRED P/N   | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-263AB                              | VB T3045C-M3/4W | 1.38            | 4W           | 50/tube       | Tube          |
| TO-263AB                              | VB T3045C-M3/8W | 1.38            | 8W           | 800/reel      | Tape and reel |

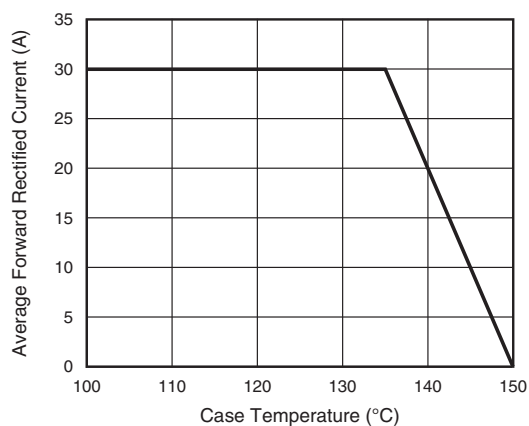
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

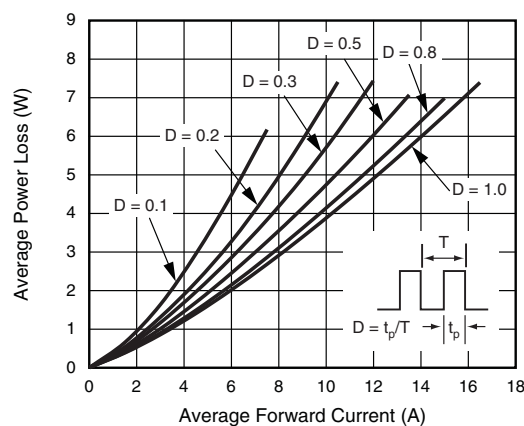


Fig. 2 - Forward Power Loss Characteristics Per Diode

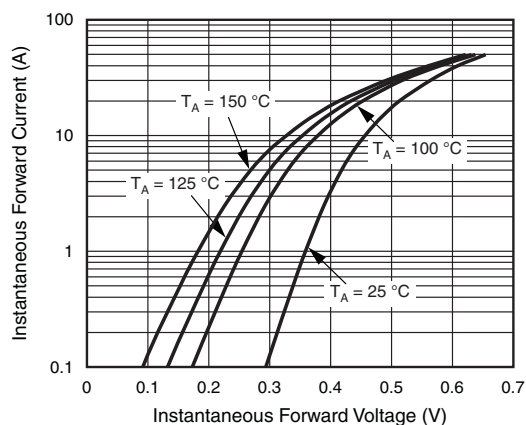


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

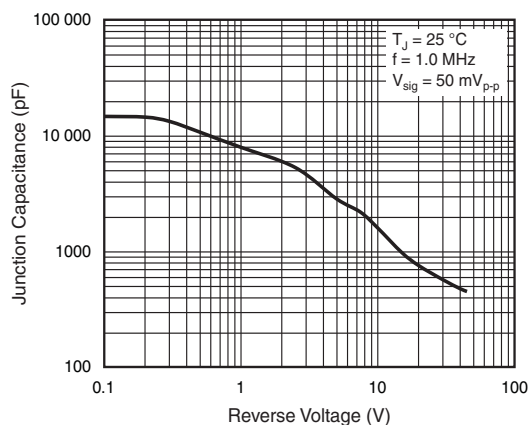


Fig. 5 - Typical Junction Capacitance Per Diode

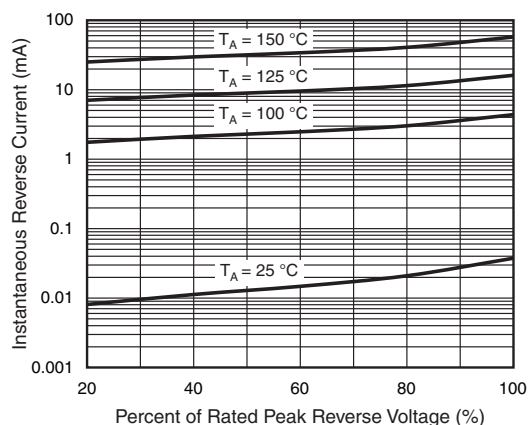


Fig. 4 - Typical Reverse Characteristics Per Diode

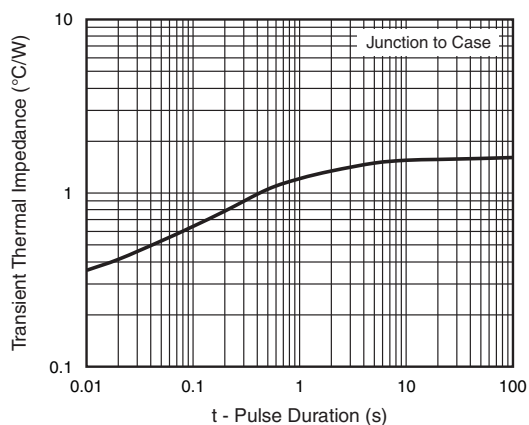
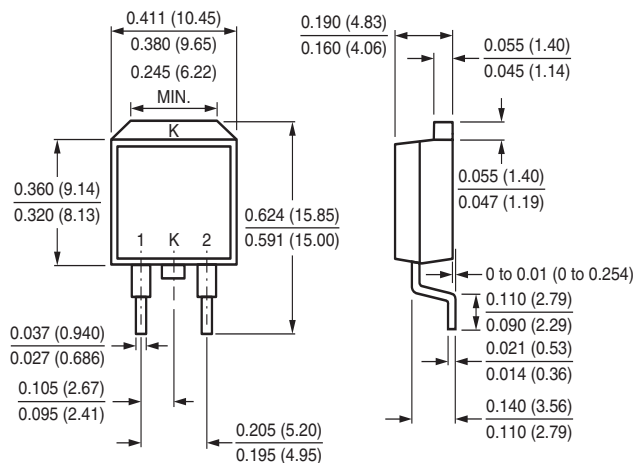


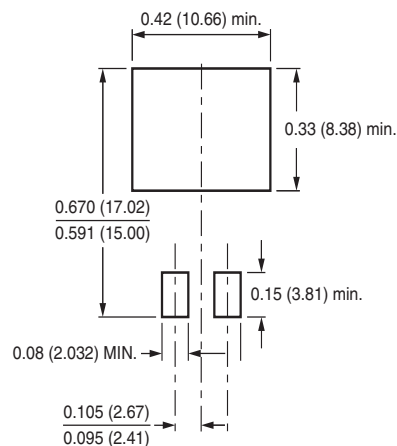
Fig. 6 - Typical Transient Thermal Impedance Per Diode

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

## D<sup>2</sup>PAK (TO-263AB)



## Mounting Pad Layout





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